

FEATURES

- 0.5 Ω typical on resistance
- 0.8 Ω maximum on resistance at 125°C
- 1.65 V to 3.6 V operation
- Automotive temperature range: -40°C to +125°C
- High current carrying capability: 300 mA continuous
- Rail-to-rail switching operation
- Fast switching times <25 ns
- Typical power consumption (<0.1 μ W)

APPLICATIONS

- MP3 players
- Power routing
- Battery-powered systems
- PCMCIA cards
- Cellular phones
- Modems
- Audio and video signal routing
- Communication systems

GENERAL DESCRIPTION

The ADG804 is a low voltage 4-channel CMOS multiplexer comprising four single channels. This device offers ultralow on resistance of less than 0.8 Ω over the full temperature range. The digital inputs can handle 1.8 V logic with a 2.7 V to 3.6 V supply.

The ADG804 switches one of four inputs to a common output, D, as determined by the 3-bit binary address lines, A0, A1, and EN. A Logic 0 on the EN pin disables the device. The ADG804 has break-before-make switching.

The ADG804 is fully specified for 3.3 V, 2.5 V, and 1.8 V supply operation. It is available in a 10-lead MSOP package.

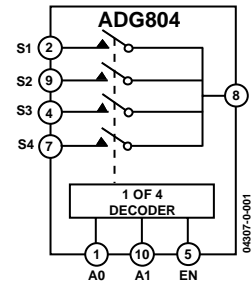
FUNCTIONAL BLOCK DIAGRAM

Figure 1.

PRODUCT HIGHLIGHTS

- <0.8 Ω over full temperature range of -40°C to +125°C.
- Single 1.65 V to 3.6 V operation.
- Operational with 1.8 V CMOS logic.
- High current handling capability (300 mA continuous current at 3.3 V).
- Low THD + N (0.02% typ).
- Small 10-lead MSOP package.

Rev. 0

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REVISION HISTORY

Revision 0: Initial Version

SPECIFICATIONS

$V_{DD} = 2.7\text{ V to }3.6\text{ V}$, $GND = 0\text{ V}$, unless otherwise noted.¹

Table 1.

| Parameter | +25°C | -40°C to +85°C | -40°C to +125°C | Unit | Test Conditions/Comments |
|--|-----------|-------------------|--------------------|-------------------|---|
| ANALOG SWITCH | | | | | |
| Analog Signal Range | | | 0 V to V_{DD} | V | |
| On Resistance (R_{ON}) | 0.5 | | | Ω typ | $V_{DD} = 2.7\text{ V}$; $V_S = 0\text{ V to }V_{DD}$, $I_S = 10\text{ mA}$; Figure 18 |
| | 0.65 | 0.75 | 0.8 | Ω max | |
| On Resistance Match between Channels (ΔR_{ON}) | 0.04 | | | Ω typ | $V_{DD} = 2.7\text{ V}$; $V_S = 0.65\text{ V}$, $I_S = 10\text{ mA}$ |
| | | 0.075 | 0.08 | Ω max | |
| On Resistance Flatness ($R_{FLAT(ON)}$) | 0.1 | | | Ω typ | $V_{DD} = 2.7\text{ V}$; $V_S = 0\text{ V to }V_{DD}$, |
| | | 0.15 | 0.16 | Ω max | $I_S = 10\text{ mA}$ |
| LEAKAGE CURRENTS | | | | | |
| Source Off Leakage I_S (OFF) | ± 0.1 | | | nA typ | $V_{DD} = 3.6\text{ V}$ |
| | ± 1 | | | nA max | $V_S = 0.6\text{ V}/3.3\text{ V}$; $V_D = 3.3\text{ V}/0.6\text{ V}$; Figure 19 |
| Drain Off Leakage I_D (OFF) | ± 0.1 | | | nA typ | $V_S = 0.6\text{ V}/3.3\text{ V}$; $V_D = 3.3\text{ V}/0.6\text{ V}$; Figure 19 |
| | ± 1 | | | nA max | |
| Channel On Leakage I_D, I_S (ON) | ± 0.1 | | | nA typ | $V_S = V_D = 0.6\text{ V or }3.3\text{ V}$; Figure 20 |
| | ± 1 | | | nA max | |
| DIGITAL INPUTS | | | | | |
| Input High Voltage, V_{INH} | | | 2 | V min | |
| Input Low Voltage, V_{INL} | | | 0.8 | V max | |
| Input Current I_{INL} or I_{INH} | 0.005 | | | μA typ | $V_{IN} = V_{INL}$ or V_{INH} |
| | | | ± 0.1 | μA max | |
| C_{IN} , Digital Input Capacitance | 4 | | | pF typ | |
| DYNAMIC CHARACTERISTICS² | | | | | |
| $t_{TRANSITION}$ | 24 | | | ns typ | $R_L = 50\ \Omega$, $C_L = 35\text{ pF}$ |
| | 30 | 32 | 35 | ns max | $V_S = 1.5\text{ V}/0\text{ V}$; Figure 21 |
| $t_{ON\ ENABLE}$ | 23 | | | ns typ | $R_L = 50\ \Omega$, $C_L = 35\text{ pF}$ |
| | 29 | 30 | 31 | ns max | $V_S = 1.5\text{ V}/0\text{ V}$; Figure 23 |
| $t_{OFF\ ENABLE}$ | 5 | | | ns typ | $R_L = 50\ \Omega$, $C_L = 35\text{ pF}$ |
| | 6 | 7 | 8 | ns max | $V_S = 1.5\text{ V}$; Figure 23 |
| Break-Before-Make Time Delay (t_{BBM}) | 20 | | | ns typ | $R_L = 50\ \Omega$, $C_L = 35\text{ pF}$ |
| Charge Injection | 28 | | 5 | ns min | $V_{S1} = V_{S2} = 1.5\text{ V}$; Figure 22 |
| Off Isolation | -67 | | | pC typ | $V_S = 1.5\text{ V}$, $R_S = 0\ \Omega$, $C_L = 1\text{ nF}$; Figure 24 |
| Channel-to-Channel Crosstalk | -75 | | | dB typ | $R_L = 50\ \Omega$, $C_L = 5\text{ pF}$, $f = 100\text{ kHz}$; Figure 25 |
| Total Harmonic Distortion (THD+N) | 0.02 | | | dB typ | $R_L = 50\ \Omega$, $C_L = 5\text{ pF}$, $f = 100\text{ kHz}$; Figure 27 |
| Insertion Loss | 0.06 | | | % | $R_L = 32\ \Omega$, $f = 20\text{ Hz to }20\text{ kHz}$, $V_S = 2\text{ V p-p}$ |
| -3 dB Bandwidth | 33 | | | dB typ | $R_L = 50\ \Omega$, $C_L = 5\text{ pF}$, $f = 100\text{ kHz}$ |
| C_S (OFF) | 24 | | | MHz typ | $R_L = 50\ \Omega$, $C_L = 5\text{ pF}$; Figure 26 |
| C_D (OFF) | 105 | | | pF typ | |
| C_D, C_S (ON) | 125 | | | pF typ | |
| POWER REQUIREMENTS | | | | | |
| I_{DD} | 0.003 | | | μA typ | $V_{DD} = 3.6\text{ V}$ |
| | | 1.0 | 4 | μA max | Digital inputs = 0 V or 3.6 V |

¹ Temperature range, Y version: $-40^\circ\text{C to }+125^\circ\text{C}$.

² Guaranteed by design, not subject to production test.

ADG804

$V_{DD} = 2.5 \text{ V} \pm 0.2 \text{ V}$, $GND = 0 \text{ V}$, unless otherwise noted.¹

Table 2.

| Parameter | +25°C | −40°C to +85°C | −40°C to +125°C | Unit | Test Conditions/Comments |
|--|-----------|----------------|-----------------|-------------------|--|
| ANALOG SWITCH | | | | | |
| Analog Signal Range | | | 0 V to V_{DD} | V | |
| On Resistance (R_{ON}) | 0.65 | | | Ω typ | $V_{DD} = 2.3 \text{ V}$; $V_S = 0 \text{ V}$ to V_{DD} ; $I_S = 10 \text{ mA}$; Figure 18 |
| | 0.77 | 0.8 | 0.88 | Ω max | |
| On Resistance Match between Channels (ΔR_{ON}) | 0.4 | | | Ω typ | $V_{DD} = 2.3 \text{ V}$; $V_S = 0.7 \text{ V}$; $I_S = 10 \text{ mA}$ |
| | | 0.08 | 0.085 | Ω max | |
| On Resistance Flatness ($R_{FLAT(ON)}$) | 0.16 | | | Ω typ | $V_{DD} = 2.3 \text{ V}$; $V_S = 0 \text{ V}$ to V_{DD} ; $I_S = 10 \text{ mA}$ |
| | | 0.23 | 0.24 | Ω max | |
| LEAKAGE CURRENTS | | | | | |
| Source Off Leakage I_S (OFF) | ± 0.1 | | | nA typ | $V_{DD} = 2.7 \text{ V}$ |
| | ± 1 | | | nA max | $V_S = 0.6 \text{ V}/2.4 \text{ V}$, $V_D = 2.4 \text{ V}/0.6 \text{ V}$; Figure 19 |
| Drain Off Leakage I_D (OFF) | ± 0.1 | | | nA typ | $V_S = 0.6/2.4 \text{ V}$, $V_D = 2.4/0.6 \text{ V}$; Figure 19 |
| | ± 1 | | | nA max | |
| Channel On Leakage I_D , I_S (ON) | ± 0.1 | | | nA typ | $V_S = V_D = 0.6 \text{ V}$ or 2.4 V ; Figure 20 |
| | ± 1 | | | nA max | |
| DIGITAL INPUTS | | | | | |
| Input High Voltage, V_{INH} | | | 1.7 | V min | |
| Input Low Voltage, V_{INL} | | | 0.7 | V max | |
| Input Current I_{INL} or I_{INH} | 0.005 | | | μA typ | $V_{IN} = V_{INL}$ or V_{INH} |
| | | | ± 0.1 | μA max | |
| C_{IN} , Digital Input Capacitance | 4 | | | pF typ | |
| DYNAMIC CHARACTERISTICS² | | | | | |
| $T_{TRANSITION}$ | 25 | | | ns typ | $R_L = 50 \Omega$, $C_L = 35 \text{ pF}$ |
| | 31 | 33 | 35 | ns max | $V_S = 1.5 \text{ V}/0 \text{ V}$; Figure 21 |
| $t_{ON \text{ ENABLE}}$ | 25 | | | ns typ | $R_L = 50 \Omega$, $C_L = 35 \text{ pF}$ |
| | 30 | 32 | 34 | ns max | $V_S = 1.5 \text{ V}/0 \text{ V}$; Figure 22 |
| $t_{OFF \text{ ENABLE}}$ | 5 | | | ns typ | $R_L = 50 \Omega$, $C_L = 35 \text{ pF}$ |
| | 7 | 8 | 9 | ns max | $V_S = 1.5 \text{ V}$; Figure 22 |
| Break-Before-Make Time Delay (t_{BBM}) | 20 | | | ns typ | $R_L = 50 \Omega$, $C_L = 35 \text{ pF}$ |
| | | | 5 | ns min | $V_{S1} = V_{S2} = 1.5 \text{ V}$; Figure 22 |
| Charge Injection | 20 | | | pC typ | $V_S = 1.25 \text{ V}$, $R_S = 0 \Omega$, $C_L = 1 \text{ nF}$; Figure 24 |
| Off Isolation | −67 | | | dB typ | $R_L = 50 \Omega$, $C_L = 5 \text{ pF}$, $f = 100 \text{ kHz}$; Figure 25 |
| Channel-to-Channel Crosstalk | −75 | | | dB typ | $R_L = 50 \Omega$, $C_L = 5 \text{ pF}$, $f = 100 \text{ kHz}$; Figure 27 |
| Total Harmonic Distortion (THD + N) | 0.022 | | | % | $R_L = 32 \Omega$, $f = 20 \text{ Hz}$ to 20 kHz , $V_S = 1.5 \text{ V}$ p-p |
| Insertion Loss | −0.06 | | | dB typ | $R_L = 50 \Omega$, $C_L = 5 \text{ pF}$, $f = 100 \text{ kHz}$ |
| −3 dB Bandwidth | 33 | | | MHz typ | $R_L = 50 \Omega$, $C_L = 5 \text{ pF}$; Figure 26 |
| C_S (OFF) | 25 | | | pF typ | |
| C_D (OFF) | 110 | | | pF typ | |
| C_D , C_S (ON) | 128 | | | pF typ | |
| POWER REQUIREMENTS | | | | | |
| I_{DD} | 0.003 | | | μA typ | $V_{DD} = 2.7 \text{ V}$ |
| | | 1 | 4 | μA max | Digital inputs = 0 V or 2.7 V |

¹ Temperature range, Y version: −40°C to +125°C.

² Guaranteed by design, not subject to production test.

$V_{DD} = 1.65 \text{ V} \pm 1.95 \text{ V}$, GND = 0 V, unless otherwise noted.¹

Table 3.

| Parameter | -40°C to | | -40°C to +125°C | Unit | Test Conditions/Comments |
|---|-----------|-------|--------------------|-------------------|---|
| | +25°C | +85°C | | | |
| ANALOG SWITCH | | | | | |
| Analog Signal Range | | | 0 V to V_{DD} | V | |
| On Resistance (R_{ON}) | 1 | | | Ω typ | $V_{DD} = 1.8 \text{ V}$; $V_S = 0 \text{ V to } V_{DD}$, $I_S = 10 \text{ mA}$ |
| | 1.4 | 2.2 | 2.2 | Ω max | |
| | 2.2 | 4 | 4 | Ω max | $V_{DD} = 1.65 \text{ V}$, $V_S = 0 \text{ V to } V_{DD}$, $I_S = 10 \text{ mA}$; Figure 18 |
| On Resistance Match between Channels (ΔR_{ON}) | 0.1 | | | Ω typ | $V_{DD} = 1.65 \text{ V}$, $V_S = 0.7 \text{ V}$, $I_S = 10 \text{ mA}$ |
| LEAKAGE CURRENTS | | | | | |
| Source Off Leakage I_S (OFF) | ± 0.1 | | | nA typ | $V_{DD} = 1.95 \text{ V}$ $V_S = 0.6 \text{ V}/1.65 \text{ V}$, $V_D = 1.65 \text{ V}/0.6 \text{ V}$; Figure 19 |
| | ± 1 | | | nA max | |
| Drain Off Leakage I_D (OFF) | ± 0.1 | | | nA typ | $V_S = 0.6/1.65 \text{ V}$, $V_D = 1.65/0.6 \text{ V}$; Figure 19 |
| | ± 1 | | | nA max | |
| Channel On Leakage I_D , I_S (ON) | ± 0.1 | | | nA typ | $V_S = V_D = 0.6 \text{ V or } 1.65 \text{ V}$; Figure 20 |
| | ± 1 | | | nA max | |
| DIGITAL INPUTS | | | | | |
| Input High Voltage, V_{INH} | | | $0.65 V_{DD}$ | V min | |
| Input Low Voltage, V_{INL} | | | $0.35 V_{DD}$ | V max | |
| Input Current I_{INL} or I_{INH} | 0.005 | | | μA typ | $V_{IN} = V_{INL}$ or V_{INH} |
| | | | ± 0.1 | μA max | |
| C_{IN} , Digital Input Capacitance | 4 | | | pF typ | |
| DYNAMIC CHARACTERISTICS² | | | | | |
| $t_{TRANSITION}$ | 32 | | | ns typ | $R_L = 50 \Omega$, $C_L = 35 \text{ pF}$ |
| | 40 | 42 | 44 | ns max | $V_S = 1.5 \text{ V}/0 \text{ V}$; Figure 21 |
| $t_{ON ENABLE}$ | 34 | | | ns typ | $R_L = 50 \Omega$, $C_L = 35 \text{ pF}$ |
| | 39 | 40 | 41 | ns max | $V_S = 1.5 \text{ V}/0 \text{ V}$; Figure 22 |
| $t_{OFF ENABLE}$ | 8 | | | ns typ | $R_L = 50 \Omega$, $C_L = 35 \text{ pF}$ |
| | 10 | 11 | 13 | ns max | $V_S = 1.5 \text{ V}$; Figure 22 |
| Break-Before-Make Time Delay (t_{BBM}) | 22 | | | ns typ | $R_L = 50 \Omega$, $C_L = 35 \text{ pF}$ |
| | | | 5 | ns min | $V_{S1} = V_{S2} = 1 \text{ V}$; Figure 22 |
| Charge Injection | 12 | | | pC typ | $V_S = 1 \text{ V}$, $R_S = 0 \text{ V}$, $C_L = 1 \text{ nF}$; Figure 24 |
| Off Isolation | -67 | | | dB typ | $R_L = 50 \Omega$, $C_L = 5 \text{ pF}$, $f = 100 \text{ kHz}$; Figure 25 |
| Channel-to-Channel Crosstalk | -75 | | | dB typ | $R_L = 50 \Omega$, $C_L = 5 \text{ pF}$, $f = 100 \text{ kHz}$; Figure 27 |
| Total Harmonic Distortion (THD + N)) | 0.14 | | | % | $R_L = 32 \Omega$, $f = 20 \text{ Hz to } 20 \text{ kHz}$, $V_S = 1.2 \text{ V p-p}$ |
| Insertion Loss | 0.08 | | | dB typ | $R_L = 50 \Omega$, $C_L = 5 \text{ pF}$, $f = 100 \text{ kHz}$ |
| -3 dB Bandwidth | 30 | | | MHz typ | $R_L = 50 \Omega$, $C_L = 5 \text{ pF}$; Figure 26 |
| C_S (OFF) | 26 | | | pF typ | |
| C_D (OFF) | 115 | | | pF typ | |
| C_D , C_S (ON) | 130 | | | pF typ | |
| POWER REQUIREMENTS | | | | | |
| I_{DD} | 0.003 | | | μA typ | $V_{DD} = 1.95 \text{ V}$ Digital inputs = 0 V or 1.95 V |
| | | 1.0 | 4 | μA max | |

¹ Temperature range, Y version: -40°C to +125°C.

² Guaranteed by design, not subject to production test.

ABSOLUTE MAXIMUM RATINGS

T_A = 25°C, unless otherwise noted.

Table 4.

| Parameter | Rating |
|-----------------------------------|---|
| V _{DD} to GND | −0.3 V to +4.6 V |
| Analog Inputs ¹ | −0.3 V to V _{DD} + 0.3 V |
| Digital Inputs ¹ | −0.3 V to +4.6 V or 10 mA, whichever occurs first |
| Peak Current, S or D | (Pulsed at 1 ms, 10% Duty Cycle Max) |
| 3.3 V Operation | 500 mA |
| 2.5 V Operation | 460 mA |
| 1.8 V Operation | 420 mA |
| Continuous Current, S or D | |
| 3.3 V Operation | 300 mA |
| 2.5 V Operation | 275 mA |
| 1.8 V Operation | 250 mA |
| Operating Temperature Range | |
| Automotive (Y Version) | −40°C to +125°C |
| Storage Temperature Range | −65°C to +150°C |
| Junction Temperature | 150°C |
| MSOP Package | |
| θ _{JA} Thermal Impedance | 206°C/W |
| θ _{JC} Thermal Impedance | 44°C/W |
| IR Reflow, Peak Temperature | 235°C |
| <20 sec | |

¹ Overvoltages at IN, S, or D are clamped by internal diodes. Current should be limited to the maximum ratings given.

ESD CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although this product features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those listed in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Only one absolute maximum rating may be applied at any one time.

Table 5. ADG804 Truth Table

| A1 | A0 | EN | ON Switch |
|----|----|----|-----------|
| x | x | 0 | None |
| 0 | 0 | 1 | S1 |
| 0 | 1 | 1 | S2 |
| 1 | 0 | 1 | S3 |
| 1 | 1 | 1 | S4 |

PIN CONFIGURATION

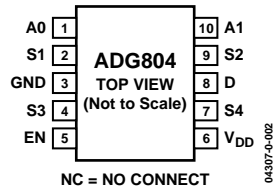


Figure 2. 10-Lead MSOP (RM-10)

Table 6. Terminology

| | |
|--------------------------------------|--|
| V _{DD} | Most positive power supply potential. |
| I _{DD} | Positive supply current. |
| GND | Ground (0 V) reference. |
| S | Source terminal. May be an input or an output. |
| D | Drain terminal. May be an input or an output. |
| EN | Active high logic control input. |
| A0, A1 | Logic control inputs. Used to select which source terminal, S1 to S4, is connected to the drain, D. |
| V _D , V _S | Analog voltage on terminals D, S. |
| R _{ON} | Ohmic resistance between D and S. |
| R _{FLAT (ON)} | Flatness is defined as the difference between the maximum and minimum value of on resistance as measured over the specified analog signal range. |
| ΔR _{ON} | On resistance match between any two channels. |
| I _{S (OFF)} | Source leakage current with the switch off. |
| I _{D (OFF)} | Drain leakage current with the switch off. |
| I _D , I _{S (ON)} | Channel leakage current with the switch on. |
| V _{INL} | Maximum input voltage for Logic 0. |
| V _{INH} | Minimum input voltage for Logic 1. |
| I _{INL (INH)} | Input current of the digital input. |
| C _{S (OFF)} | Off switch source capacitance. Measured with reference to ground. |
| C _{D (OFF)} | Off switch drain capacitance. Measured with reference to ground. |
| C _D , C _{S (ON)} | On switch capacitance. Measured with reference to ground. |
| C _{IN} | Digital input capacitance. |
| t _{ON (EN)} | Delay time between the 50% and the 90% points of the digital input and switch on condition. |
| t _{OFF (EN)} | Delay time between the 50% and the 90% points of the digital input and switch off condition. |
| t _{TRANSITION} | Delay time between the 50% and the 90% points of the digital input and switch on condition when switching from one address state to the other. |
| t _{BBM} | On or off time measured between the 80% points of both switches when switching from one to another. |
| Charge Injection | A measure of the glitch impulse transferred from the digital input to the analog output during on-off switching. |
| Off Isolation | A measure of unwanted signal coupling through an off switch. |
| Crosstalk | A measure of unwanted signal which is coupled through from one channel to another as a result of parasitic capacitance. |
| -3 dB Bandwidth | The frequency at which the output is attenuated by 3 dB. |
| On Response | The frequency response of the on switch. |
| Insertion Loss | The loss due to the on resistance of the switch. |
| THD + N | The ratio of the harmonic amplitudes plus noise of a signal to the fundamental. |

TYPICAL PERFORMANCE CHARACTERISTICS

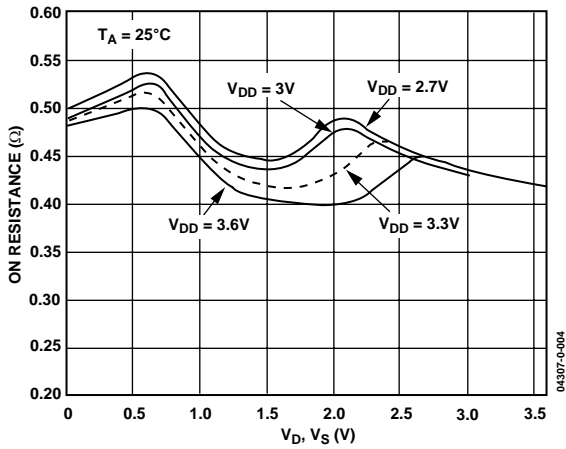


Figure 3. On Resistance vs. V_D (V_S) $V_{DD} = 2.7V$ to $3.6V$

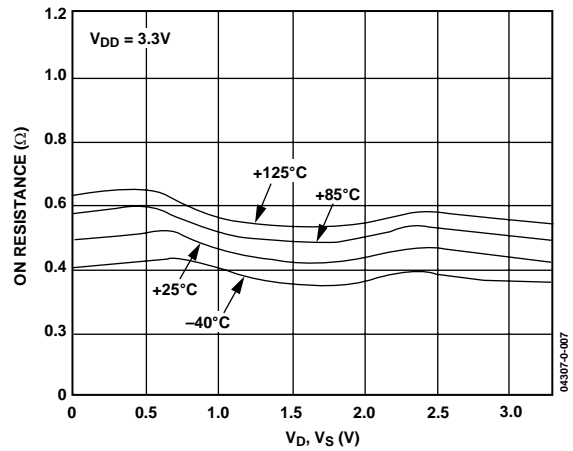


Figure 6. On Resistance vs. V_D (V_S) for Different Temperature, $V_{DD} = 3.3V$

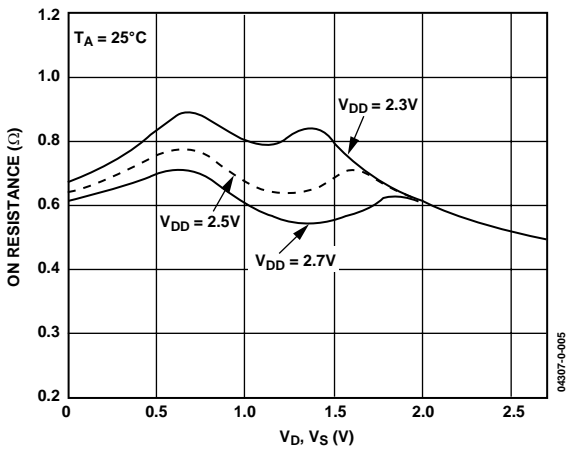


Figure 4. On Resistance vs. V_D (V_S) $V_{DD} = 2.5V \pm 0.2V$

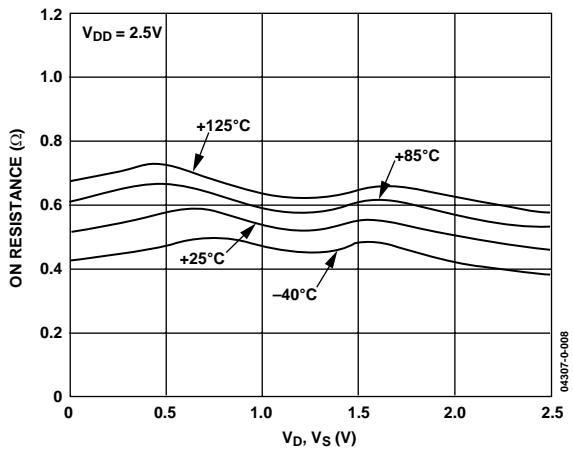


Figure 7. On Resistance vs. V_D (V_S) for Different Temperature, $V_{DD} = 2.5V$

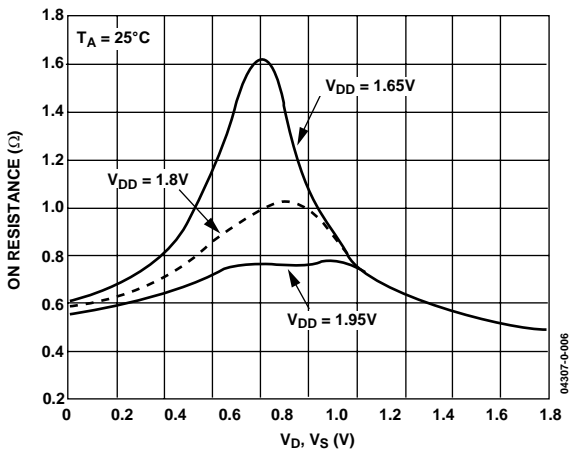


Figure 5. On Resistance vs. V_D (V_S) $V_{DD} = 1.8 \pm 0.15V$

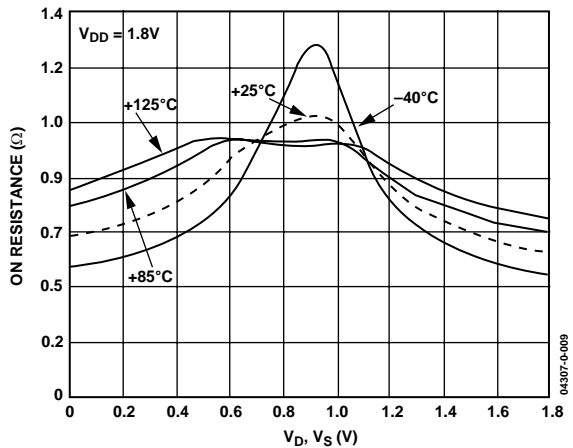


Figure 8. On Resistance vs. V_D (V_S) for Different Temperature, $V_{DD} = 1.8V$

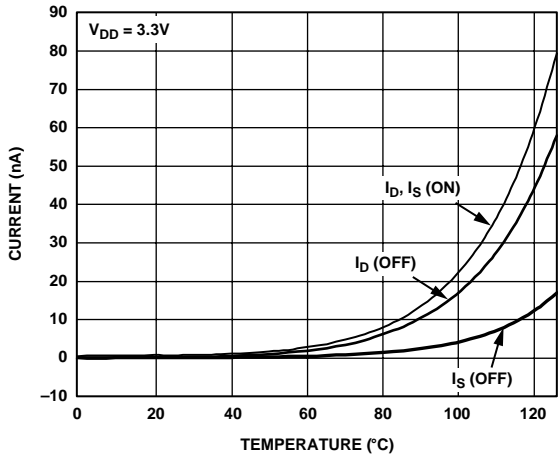


Figure 9. Leakage Current vs. Temperature, $V_{DD} = 3.3V$

04307-0-010

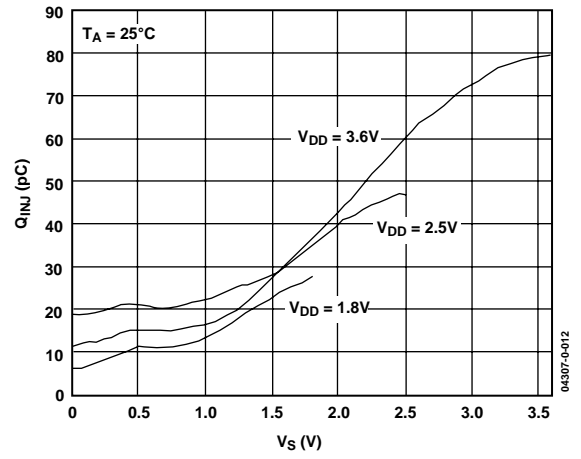


Figure 12. Charge Injection vs. Source Voltage, $V_{DD} = 1.8V$

04307-0-012

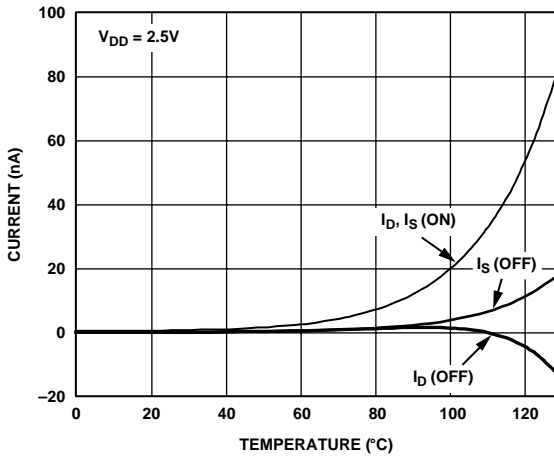


Figure 10. Leakage Current vs. Temperature, $V_{DD} = 2.5V$

04307-0-011

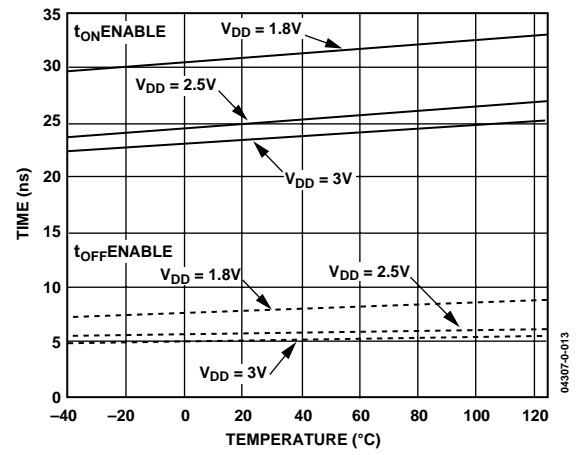


Figure 13. t_{ON}/t_{OFF} Times vs. Temperature

04307-0-013

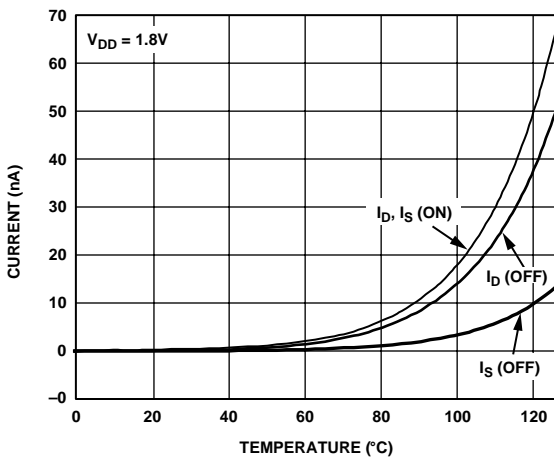


Figure 11. Leakage Current vs. Temperature, $V_{DD} = 1.8V$

04307-0-017

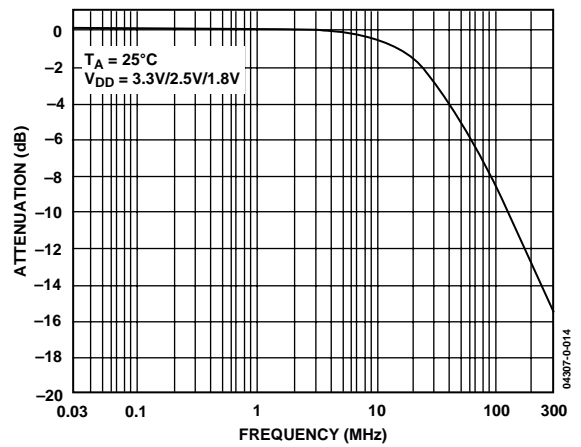


Figure 14. Bandwidth

04307-0-014

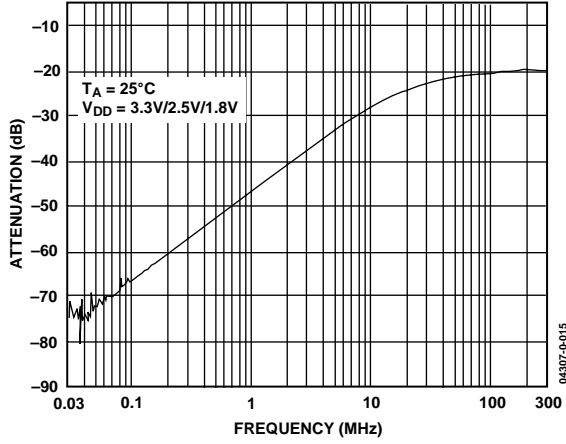


Figure 15. Off Isolation vs. Frequency

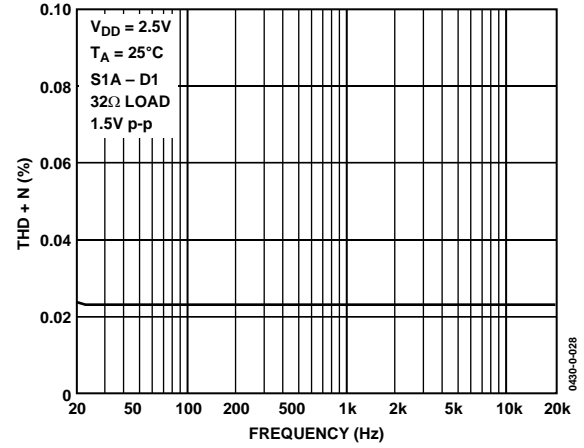


Figure 17. Total Harmonic Distortion + Noise

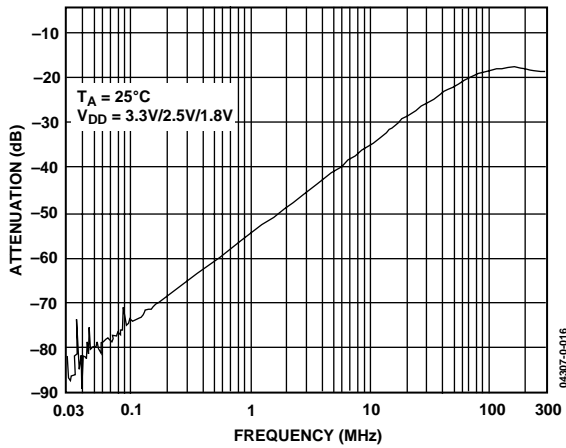


Figure 16. Crosstalk vs. Frequency

TEST CIRCUITS

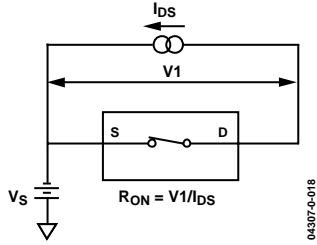


Figure 18. On Resistance

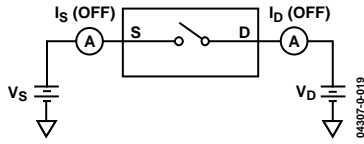


Figure 19. Off Leakage

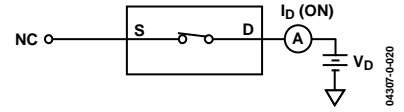


Figure 20. On Leakage

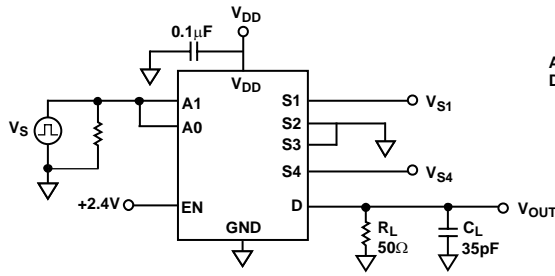


Figure 21. Switching Time of Multiplexer, $t_{\text{TRANSITION}}$

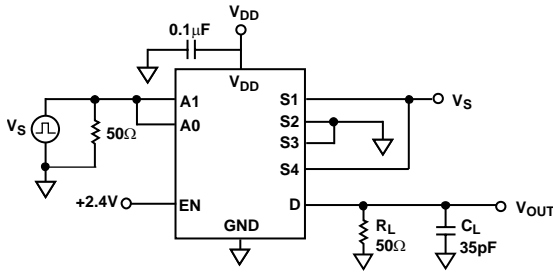
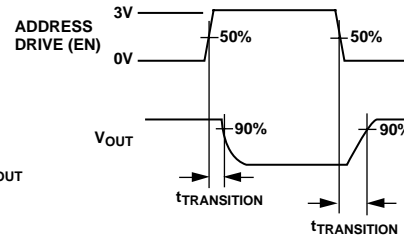


Figure 22. Break-Before-Make Time Delay, t_{BBM}

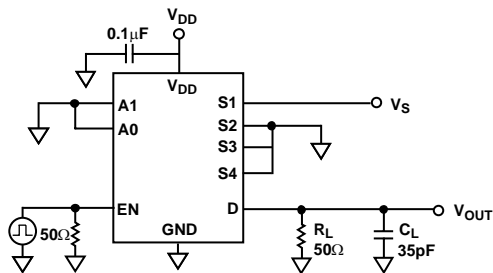
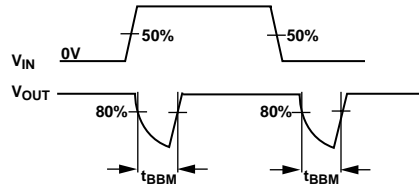
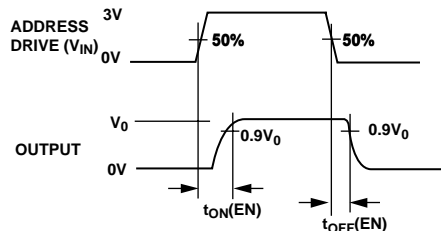


Figure 23. Enable Delay, $t_{\text{ON}}(\text{EN})$, $t_{\text{OFF}}(\text{EN})$



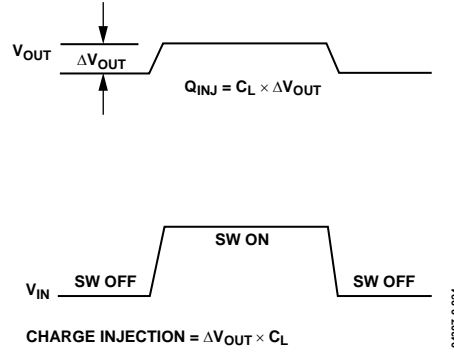
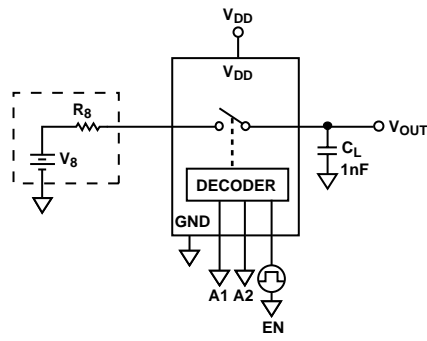


Figure 24. Charge Injection

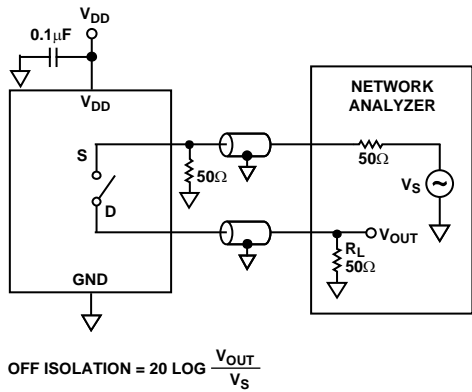


Figure 25. Off Isolation

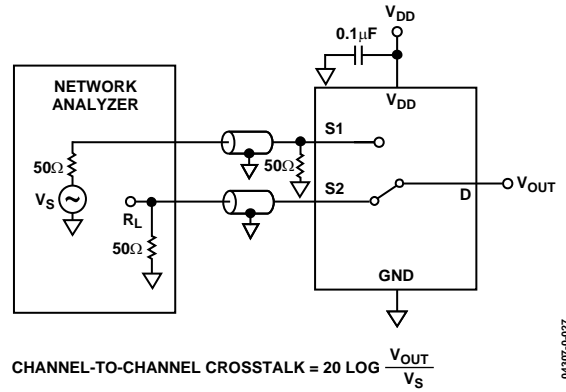


Figure 27. Channel-to-Channel Crosstalk

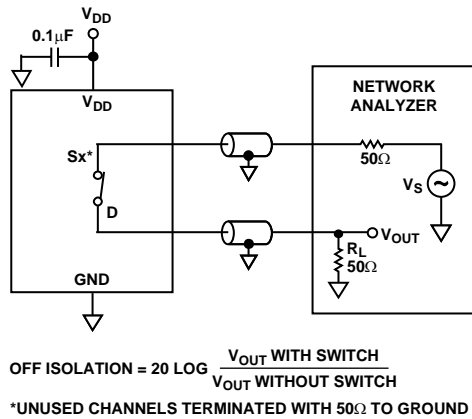


Figure 26. Bandwidth

OUTLINE DIMENSIONS

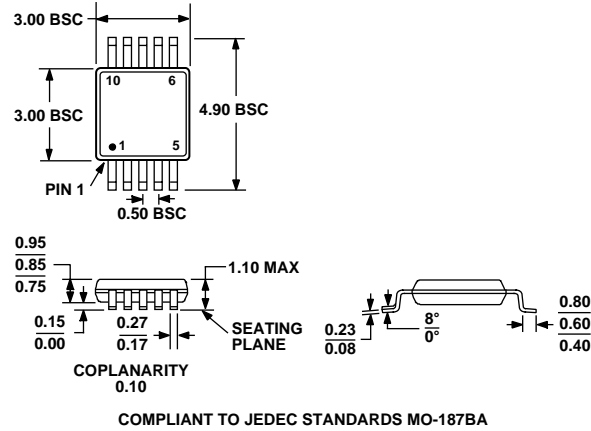


Figure 28. 10-Lead Mini Small Outline Package [MSOP] (RM-10)
Dimensions shown in millimeters

ORDERING GUIDE

| Model | Temperature Range | Package Description | Package Option | Branding ¹ |
|-----------------|-------------------|-----------------------------------|----------------|-----------------------|
| ADG804YRM | -40°C to +125°C | Mini Small Outline Package (MSOP) | RM-10 | S1A |
| ADG804YRM-REEL | -40°C to +125°C | Mini Small Outline Package (MSOP) | RM-10 | S1A |
| ADG804YRM-REEL7 | -40°C to +125°C | Mini Small Outline Package (MSOP) | RM-10 | S1A |

¹ Branding on this package is limited to three characters due to space constraints.

ADG804

NOTES

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